

Vishay Siliconix

# Low Voltage, Dual SPDT Analog Switch with Charge Pump

#### **DESCRIPTION**

The DG2616, DG2617, DG2618 are monolithic CMOS analog switching products designed for high performance switching of analog signals. Combining low power, high speed, low on-resistance and small physical size, the DG2616, DG2617, DG2618 are ideal for portable and battery powered applications.

The DG2616, DG2617, DG2618 have built-in charge-pump circuitry which lowers the minimum supply voltage to  $\pm$  1.5 V while maintaining low on-resistance. The Control circuitry allows the DG2616, DG2617, DG2618 to operate in different configurations.

Built on Vishay Siliconix's low voltage process, the DG2616, DG2617, DG2618 has an epitaxial layer that prevents latch-up. Break-before-make is guaranteed.

The DG2616, DG2617, DG2618 are manufactured in space saving DFN-10 ( $3.0 \times 3.0 \text{ mm}$ ). And as a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations and is 100 % RoHS compliant.

### **FEATURES**

- Low voltage operation (1.5 V to 3.6 V)
- Low on-resistance  $R_{ON}$ : 4.2  $\Omega$  typ. at 2.7 V
- Fast switching:  $t_{ON} = 39 \text{ ns}$  $t_{OFF} = 8 \text{ ns}$

DFN-10 package



ROHS

#### **BENEFITS**

- Reduced power consumption
- High accuracy
- · Reduce board space
- TTL/1.8 V logic compatible
- · High bandwidth

### **APPLICATIONS**

- · Cellular phones
- · Audio and video signal routing
- PCMCIA cards
- · Battery operated systems

#### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

TRUTH TABLE DG2616							
Logic NC1, 2 NO1, 2							
0	ON	OFF					
1	OFF	ON					

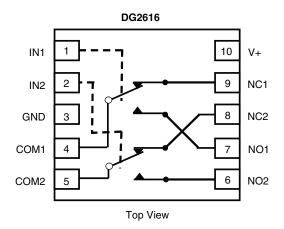
TRUTH TABLE DG2617							
SHDN/EN Logic	IN Logic	NC1, 2	NO1, 2	Charge Pump			
0	0	ON	OFF	ON			
0	1	OFF	ON	ON			
1	0	ON	OFF	OFF			
1	1	OFF	ON	OFF			

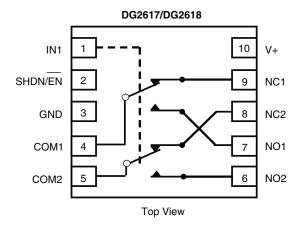
TRUTH TABLE DG2618							
SHDN/EN Logic	Charge Pump						
0	0	ON	OFF	ON			
0	1	OFF	ON	ON			
1	х	OFF	OFF	OFF			

ORDERING INFORMATION						
Temp. Range Package Part Number						
- 40 °C to 85 °C	DFN-10	DG2616DN-T1-E4 DG2617DN-T1-E4 DG2618DN-T1-E4				

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<b>ABSOLUTE MAXIMUM RATINGS</b> T <sub>A</sub> = 25 °C, unless otherwise noted						
Parameter		Limit	Unit			
Reference to GND	V+	- 0.3 to 6.0	V			
Reference to GND	IN, COM, NC, NO <sup>a</sup>	- 0.3 to (V+ + 0.3)	v			
Current (Any terminal except NO, NC or	COM)	30				
Continuous Current (NO, NC, or COM)		± 150	mA			
Peak Current (Pulsed at 1 ms, 10 % Dut	y Cycle)	± 300				
Storage Temperature (D-Suffix)		- 65 to 150	°C			
Package Solder Reflow Conditions <sup>d</sup>						
Power Dissipation (Packages) <sup>b</sup> DFN-10 <sup>c</sup>		1191	mW			

#### Notes

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 14.9 mW/°C above 70 °C
- d. Manual soldering with iron is not recommended for leadless components. The DFN-10 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.



		Test Conditions Otherwise Unless Specified			<b>Limits</b> - 40 °C to 85 °C		
Parameter	Symbol	$V+ = 3 V, \pm 10 \%, V_{IN} = 0.5 \text{ or } 1.4 \text{ V}^e$	Temp.a	Min.b	Typ. <sup>c</sup>	Max.b	Unit
Analog Switch							
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC},$		Full	0		V+	V
Analog Signal hange	V <sub>COM</sub>		ı un	· ·		VT	
		$V+ = 1.5 \text{ V}, V_{COM} = 1.5 \text{ V}, I_{NO}, I_{NC} = 10 \text{ mA}$	Room Full		5.3	7.0 8.0	
		$V+ = 2.7 \text{ V}, V_{COM} = 1.5 \text{ V}, I_{NO}, I_{NC} = 10 \text{ mA}$	D		4.2	7.0	
On-Resistance	R <sub>ON</sub>	$V+ = 2.7 \text{ V}, V_{COM} = 2.7 \text{ V}, I_{NO}, I_{NC} = 10 \text{ mA}$	Room		4.7	7.0	
			Full			8.0	
		$V+ = 3.6 \text{ V}, V_{COM} = 3.6 \text{ V}, I_{NO}, I_{NC} = 10 \text{ mA}$	Room		5.5	7.0	0
		V 1 = 0.0 V, V COM = 0.0 V, INO, INC = 10 IIIV	Full			8.0	Ω
R <sub>ON</sub> Flatness <sup>d</sup>	R <sub>ON</sub> Flatness	$V+ = 2.7 \text{ V}, V_{COM} = 1.5 \text{ V}, 2.7 \text{ V},$	Room		0.6	2.0	
R <sub>ON</sub> Match <sup>d</sup>	ΔR <sub>ON</sub>	$I_{NO}$ , $I_{NC} = 10 \text{ mA}$	Room		0.1		
On Bosistanos (Shutdown)	P	V+ = 3.6 V V 1.7 V lue lue = 10 mA	Room		15	20	
On Resistance (Shutdown)	R <sub>SHDN</sub>	$V + = 3.6 \text{ V}, V_{COM} = 1.7 \text{ V}, I_{NO}, I_{NC} = 10 \text{ mA}$	Full			21	
Switch Off Leakage Current	I <sub>NO(off)</sub> , I <sub>NC(off)</sub>		Room	- 2		2	
		$V+ = 3.6 V, V_{NO}, V_{NC} = 0.3 V/3.3 V,$	Full	- 10		10	
		$V_{COM} = 3.3 \text{ V}/0.3 \text{ V}$	Room	- 2		2	nA
			Full	- 10		10	
Channel-On Leakage	loou()	$V + = 3.6 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 0.3 \text{ V}/3.3 \text{ V}$	Room	- 2		2	
Current	ICOM(on)	v+ = 0.0 v, v <sub>NO</sub> , v <sub>NC</sub> = v <sub>COM</sub> = 0.0 v/0.0 v	Full	- 10		10	
Digital Control							
Input High Voltage	$V_{INH}$	V+ = 1.5 V	<u> </u>	1.0			
	- IIVIT	V+ = 2.7 V to 3.6 V	Full	1.4			٧
Input Low Voltage	V <sub>INL</sub>	V+ = 1.5 V	_			0.4	
-		V+ = 2.7 V to 3.6 V				0.5	
Input Capacitance	C <sub>in</sub>		Full		3.2		pF
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	$V_{IN} = 0$ or $V+$	Full	- 1		1	μΑ
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>		Room		39	69	
Turn on Time	ON	$V+ = 2.7 \text{ or } 3.6 \text{ V}, V_{NO} \text{ or } V_{NC} = 1.5 \text{ V},$	Full			76	
Turn-Off Time	t <sub>OFF</sub>	$R_L = 50 \Omega$ , $C_L = 35 pF$	Room		9	39	ns
		11 <u>L</u> = 30 12, 3 <u>L</u> = 30 pt	Full			41	
Break-Before-Make Time	t <sub>d</sub>	<u> </u>	Full	1			ļ
Charge Injection <sup>d</sup>	Q <sub>INJ</sub>	$C_L = 1 \text{ nF, } V_{GEN} = 0 \text{ V, } R_{GEN} = 0 \Omega$	Room		7		рC
Off In alastic and	OIDD	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	]		- 77		
Off-Isolation <sup>d</sup>	OIRR	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 100 MHz$	Daam		- 32		dE
	· ·	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$	1.00		- 80		42
Crosstalk <sup>d, f</sup>	X <sub>TALK</sub>	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 100 MHz$			- 32		
N <sub>O</sub> , N <sub>C</sub> Off Capacitance <sup>d</sup>	C <sub>NO(off)</sub>		Room		9		
NO, NC On Capacitance	C <sub>NC(off)</sub>	4 A MIL-	Room		7		
	C <sub>NO(on)</sub>	f = 1 MHz	Room		21		pF
Channel-On Capacitance <sup>d</sup>	C <sub>NC(on)</sub>				19		ł

# DG2616, DG2617, DG2618

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SPECIFICATIONS V+ = 3 V									
		Test Conditions Otherwise Unless Specified		Limits - 40 °C to 85 °C					
Parameter	Symbol	$V+ = 3 V, \pm 10 \%, V_{IN} = 0.5 \text{ or } 1.4 V^{e}$	Temp.a	Min.b	Typ.c	Max.b	Unit		
Power Supply									
Power Supply Range	V+			1.5		3.6	V		
Power Supply Current	l+	$V+ = 3.6 \text{ V}, V_{IN} = 0 \text{ or } V+, \text{SHDN/}\overline{\text{EN}} = 0 \text{ V}$	Full		104	300	^		
Fower Supply Current	I+	$V+ = 3.6 \text{ V}, V_{IN} = 0 \text{ or } V+, \text{SHDN/}\overline{EN} = V+$	Tull		0.1	2	μΑ		

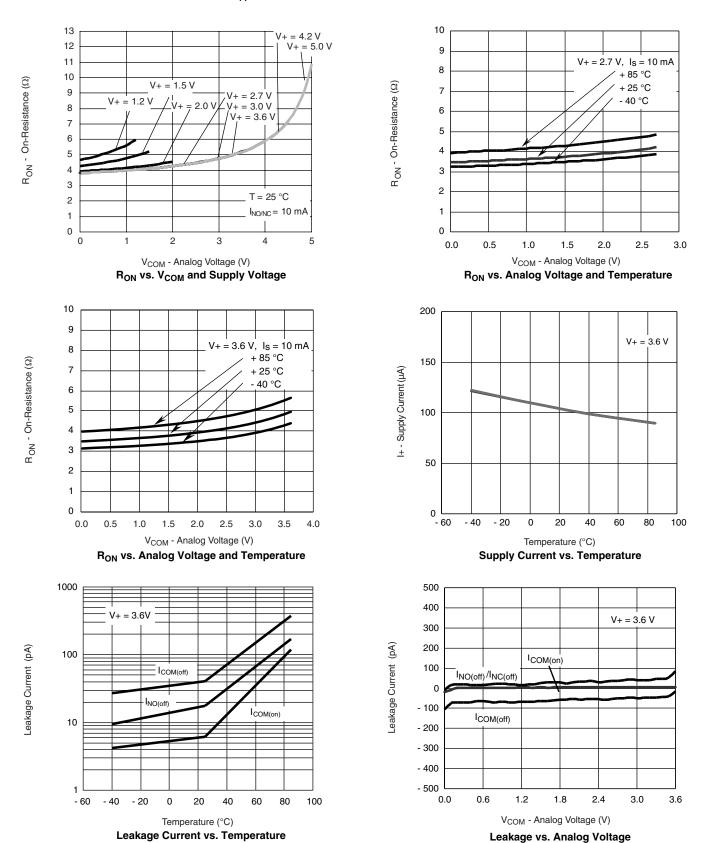
#### Notes:

- a. Room = 25  $^{\circ}$ C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, not subjected to production test.
- e. V<sub>IN</sub> = input voltage to perform proper function.
- f. Crosstalk measured between channels.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



### **TYPICAL CHARACTERISTICS** $T_A = 25$ °C, unless otherwise noted

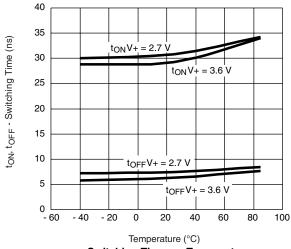


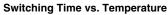
# DG2616, DG2617, DG2618

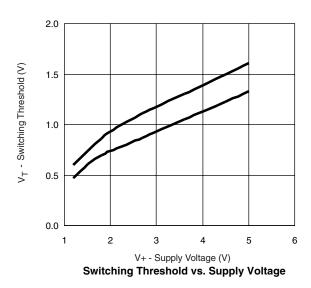
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### **TYPICAL CHARACTERISTICS** $T_A = 25$ °C, unless otherwise noted

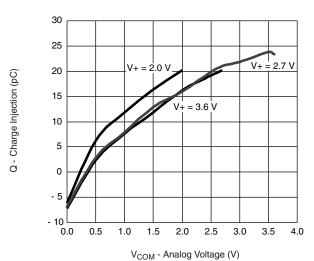






10 Loss 0 - 10 LOSS, OIRR, X<sub>TALK</sub> (dB) - 20 - 30 - 40 - 50 OIRR - 60 - 70 - 80  $R_L = 50 \Omega$ - 90 - 100 100k 100M Frequency (Hz)

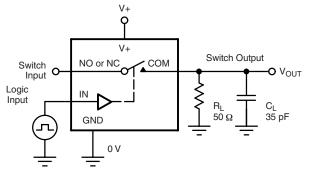
Insertion Loss, Off-Isolation Crosstalk vs. Frequency



Charge Injection vs. Analog Voltage



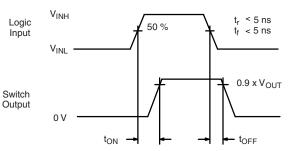
### **TEST CIRCUITS**



C<sub>L</sub> (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left( \frac{R_L}{R_L + R_{ON}} \right)$$

C<sub>L</sub> (includes fixture and stray capacitance)



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

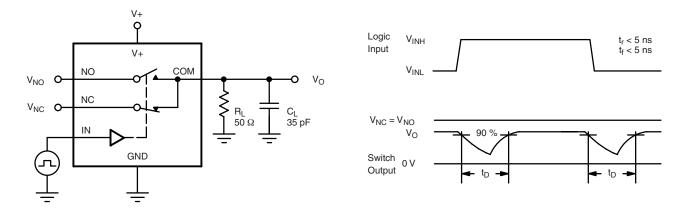


Figure 2. Break-Before-Make Interval

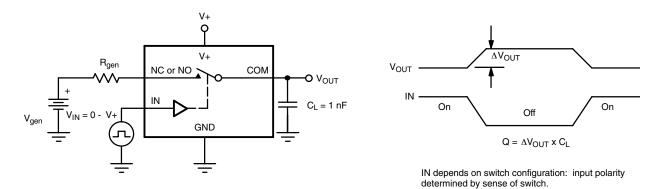


Figure 3. Charge Injection

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### **TEST CIRCUITS**



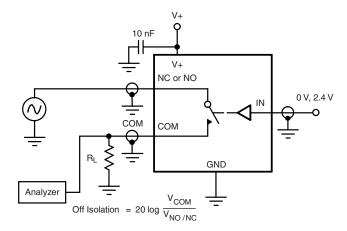


Figure 4. Off-Isolation

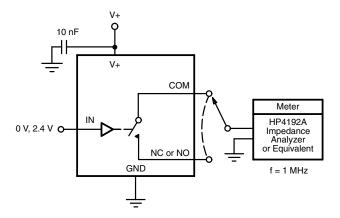
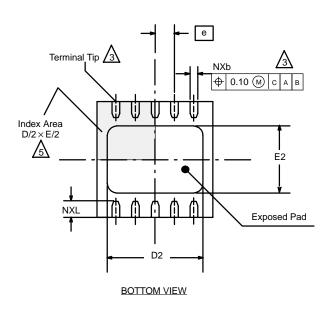


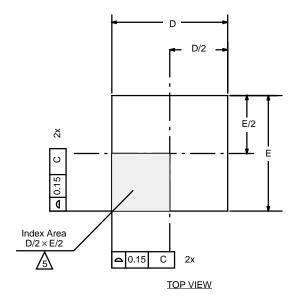
Figure 5. Channel Off/On Capacitance

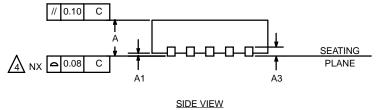
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### **DFN-10 LEAD (3 X 3)**







### NOTES:

1. All dimensions are in millimeters and inches.

N is the total number of terminals.

Dimension b applies to metallized terminal and is measured between 0.15 and 0.30 mm from terminal tip.  $\,$ 



Coplanarity applies to the exposed heat sink slug as well as the



The pin #1 identifier may be either a mold or marked feature, it must be located within the zone iindicated.

	МІ	LLIMETE	RS	INCHES				
Dim	Min	Nom	Max	Min	Nom	Max		
Α	0.80	0.90	1.00	0.031	0.035	0.039		
<b>A</b> 1	0.00	0.02	0.05	0.000	0.001	0.002		
А3		0.20 BSC			0.008 BSC			
b	0.18	0.23	0.30	0.007 0.009 0.012				
D		3.00 BSC			0.118 BSC			
D2	2.20	2.38	2.48	0.087	0.094	0.098		
Е	3.00 BSC				0.118 BSC			
E2	1.49	1.64	1.74	0.059	0.065	0.069		
е		0.50 BSC		0.020 BSC				
L	0.30	0.40	0.50	0.012	0.016	0.020		
*Use millir	meters as the	primary meas	surement.	•	•			
ECN: S-42	2134—Rev. A	, 29-Nov-04	•			•		

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